2SB1230 : PNP Epitaxial Planar Silicon Transistor 2SD1840 : NPN Triple Diffused Planar Silicon Transistor



2SB1230/2SD1840

100V/4A Switching Applications

Applications

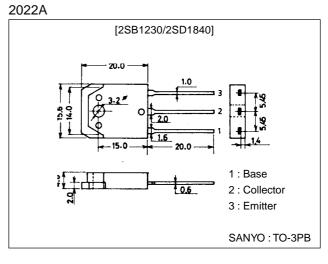
• Motor drivers, relay drivers, converters and other general high-current switching applications.

Features

- · Large current capacity and wide ASO.
- \cdot Low saturation voltage.

Package Dimensions

unit:mm



():2SB1230

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)110	V
Collector-to-Emitter Voltage	VCEO		(–)100	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	۱ _C		(–)15	А
Collector Current (Pulse)	ICP		(–)25	А
Base Current	IB		(–)5	Α
Collector Dissipation	PC		3.0	W
		Tc=25°C	100	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falanetei	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)100V, I _E =0			(–)0.1	mA
Emitter Cutoff Current	IEBO	V _{EB} =(-)5V, I _C =0			(–)0.1	mA
DC Current Gain	h _{FE} 1	V _{CE} =(-)2V, I _C =(-)1.5A	50*		140*	
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)6A	20			
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)6A, I _B =(-)0.6A			(–)0.8	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)6A, I _B =(-)0.6A			(–)1.5	V

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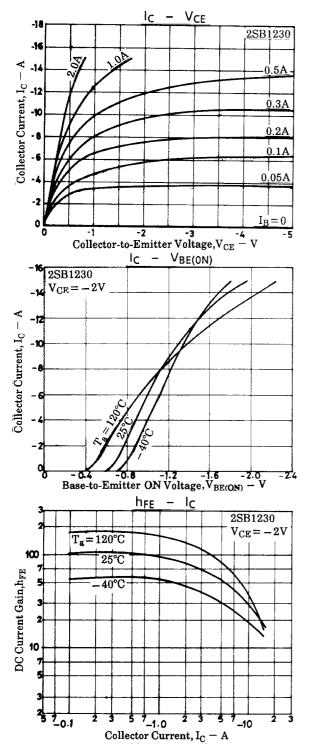
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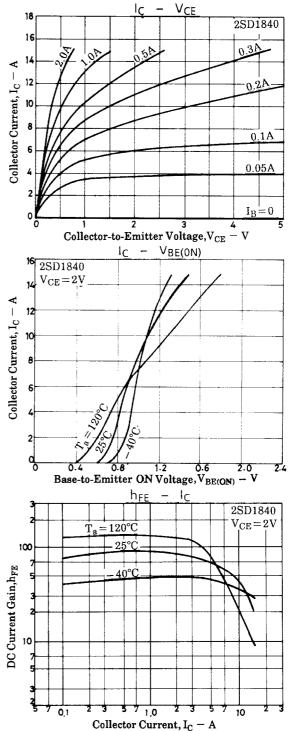
2SB1230/2SD1840

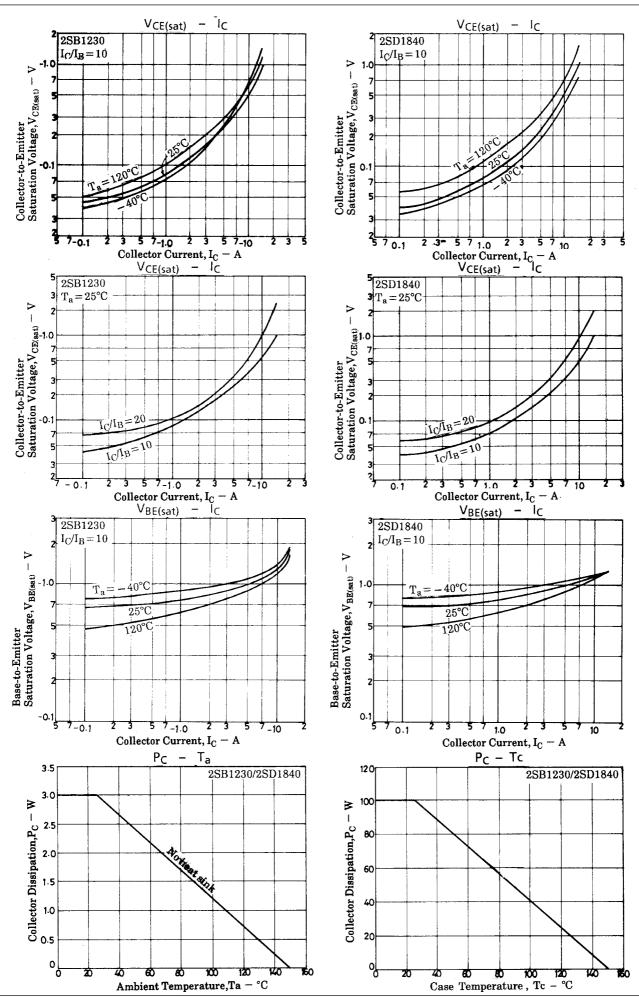
Parameter	Symbol	Conditions	Ratings			Unit
Falanielei	Symbol	Conditions	min	typ	max	Onit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)1mA, I _E =0	(–)110			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(−)5mA, R _{BE} =∞	(–)100			V
Emitter-to-Base Breakdown Votage	V _{(BR)EBO}	I _E =(–)1mA, I _C =0	(–)6			V

* : For the h_{FE}1 of the 2SB1230/2SD1840, specify two ranks or more in principle.

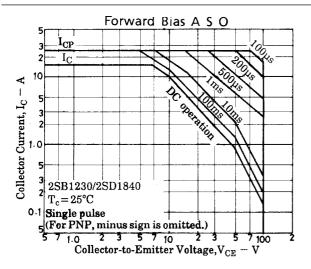
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